

100V PNP LOW SATURATION TRANSISTOR IN U-DFN2020-3

Features

- BVCE0 > -100V
- hFE Specified up to -3A for High Current Gain Hold Up
- Low Profile 0.6mm High Package for Thin Applications
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e.: parts gualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please refer to the related automotive grade (Q-suffix) part. A listing can be found at

https://www.diodes.com/products/automotive/automotiveproducts/.

This part is qualified to JEDEC standards (as references in AEC-Q) for High Reliability.

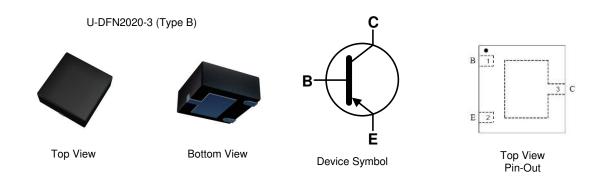
https://www.diodes.com/guality/product-definitions/

Mechanical Data

- Case: U-DFN2020-3 (Type B)
- Nominal Package Height: 0.6mm •
- Case Material: Molded Plastic. "Green" Molding Compound. UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish NiPdAu, Solderable per MIL-STD-202, Method 208 (e4)
- Weight: 0.01 grams (Approximate)

Applications

- **DC-DC Converters**
- **Charging Circuits**
- Motor Control
- **Power Switches**



Ordering Information (Note 4)

	Part Number	Marking	Reel Size (inches)	Tape Width (mm)	Quantity Per Reel		
D	XTP58100CFDB-7	2E6	7	8	3,000		
Notes:	Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.						

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



2E6 = Product Type Marking Code YM = Date Code Marking Y = Year (ex: G = 2019)M = Month (ex: 9 = September)

Date Code Key	
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Year	2019		2020	2021		2022	2023		2024	2025		2026
Code	G		Н			J	K		L	М		Ν
Month	Jan	Feb	Mar	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D



Absolute Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Parameter	Symbol	Limit	Unit
Collector-Base Voltage	Vсво	-100	
Collector-Emitter Voltage	VCEO	-100	V
Emitter-Base Voltage	VEBO	-7	
Peak Pulse Current	Ісм	-4	۸
Continuous Collector Current	lc	-2	A

Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit	
Power Dissipation	(Note 5)	D-	0.69	w	
Fower Dissipation	(Note 6)	PD	1.25	vv	
Thermal Resistance, Junction to Ambient	(Note 5)	P	180	°C/W	
Thermal Resistance, Junction to Ambient	(Note 6)	R _{0JA}	100	°C/W	
Operating and Storage Temperature Range	TJ, TSTG	-55 to +150	°C		

ESD Ratings (Note 7)

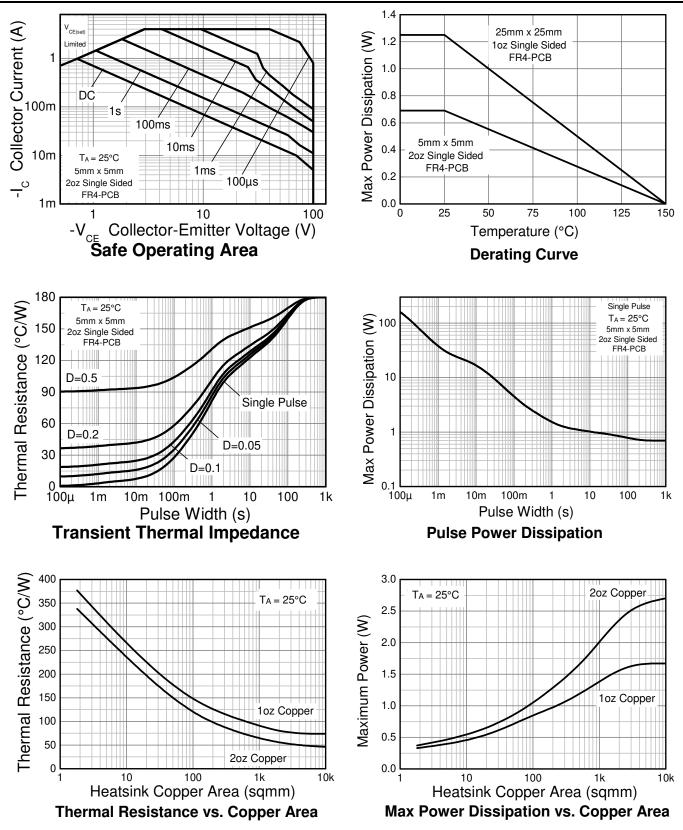
Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	ЗA
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

Notes: 5. For a device mounted with the exposed collector on 5mm x 5mm 2oz copper on single sided FR4 PCB; device is measured under still air conditions whilst operating in the steady state.

6. Same as Note (5) except the exposed collector pad is mounted on 25mm x 25mm 1oz copper.
7. Refer to JEDEC specification JESD22-A114 and JESD22-A115.



Thermal Characteristics and Derating Information





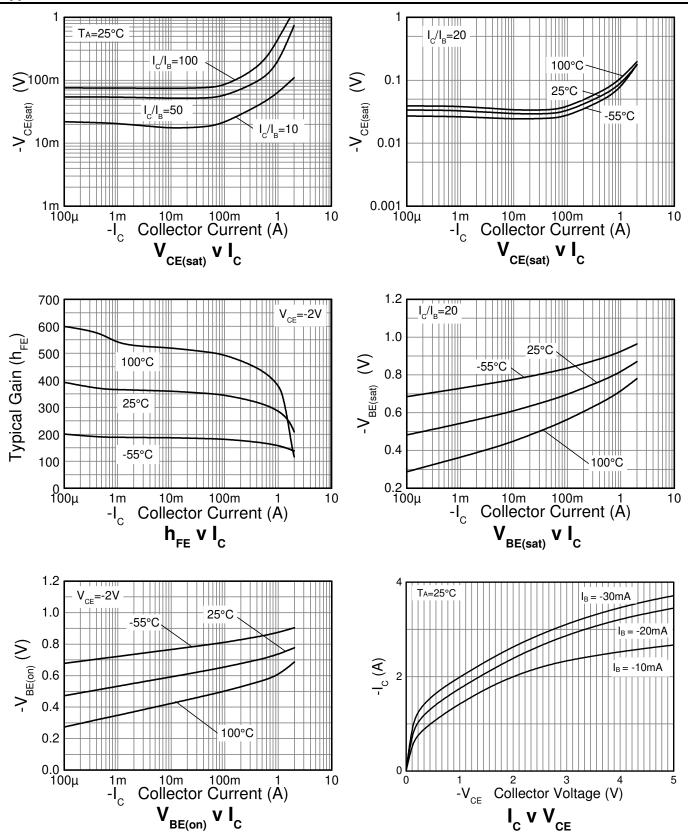
Electrical Characteristics (@T_A = +25°C, unless otherwise specified)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
Collector-Base Breakdown Voltage	ВУсво	-100	_	—	V	Ic = -100μA	
Collector-Emitter Breakdown Voltage (Note 8)	BVCEO	-100	_	—	V	Ic = -10mA	
Emitter-Base Breakdown Voltage	BV _{EBO}	-7	—	-	V	I _E = -100μA	
Collector Cutoff Current	Ісво	—	_	-100	nA	Vcb = -80V	
Emitter Cutoff Current	IEBO	—	—	-100	nA	VEB = -6V	
Collector Emitter Cutoff Current	ICES	—	_	-100	nA	V _{CES} = -80V	
		160	260	_		Ic = -500mA, Vce = -2V	
Static Forward Current Transfer Ratio (Note 8)	b	150	240	_		Ic = -1A, Vce = -2V	
	hfe	90	180	_	_	Ic = -2A, Vce = -2V	
		15	60	—		Ic = -3A, Vce = -2V	
		—	-45	-70	mV	Ic = -0.5A, I _B = -50mA	
Collector-Emitter Saturation Voltage (Note 8)	VCE(sat)	—	-95	-150		Ic = -1A, I _B = -50mA	
		—	-125	-185		Ic = -2A, I _B = -200mA	
Base-Emitter Turn-On Voltage (Note 8)	V _{BE(on)}	_	-0.75	-0.9	V	$I_{C} = -2A, V_{CE} = -2V$	
Base-Emitter Saturation Voltage (Note 8)	V _{BE(sat)}	—	-0.75	-0.9	V	I _C = -1A, I _B = -10mA	
Output Capacitance	Cobo	—	30	_	pF	V _{CB} = -10V, f = 1MHz	
Transition Frequency	f⊤	—	135	_	MHz	V _{CE} = -10V, I _C = -100mA, f = 100MHz	
Delay Time	td	_	15	_			
Rise Time	tr	_	60	_			
Turn-On Time	ton	—	75	—		Vcc = -9V, Ic = -2A	
Storage Time	ts	_	485	—	ns	I _{B1} = -I _{B2} = -0.1A	
Fall Time	t _f	_	155	—			
Turn-Off Time	toff		640	—			

Note: 8. Measured under pulsed conditions. Pulse width \leq 300µs. Duty cycle \leq 2%.



Typical Electrical Characteristics (@TA = +25°C, unless otherwise specified.)

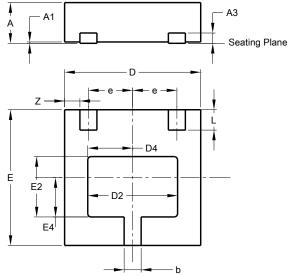




Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

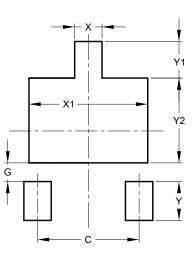
U-DFN2020-3 (Type B)



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Dim	Min	Max	Тур						
Α	0.57	0.63	0.60						
A1	0.00	0.05	0.02						
A3			0.152						
b	0.20	0.30	0.25						
D	1.950	2.075	2.00						
D2	1.22	1.42	1.32						
D4	0.56	0.76	0.66						
E	1.950	2.075	2.00						
E2	0.79	0.99	0.89						
E4	0.48	0.68	0.58						
е	_	_	0.65						
L	0.25	0.35	0.30						
Z	_	_	0.225						
All	Dimens	ions in I	mm						

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



U-DFN2020-3 (Type B)

Dimensions	Value (in mm)
С	1.300
G	0.240
Х	0.350
X1	1.520
Y	0.500
Y1	0.470
Y2	1.090



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